Quantum corrections to the conductivity and Hall coe cient of a 2D electron gas in a dirty A IG aA s/G aA s/A IG aA s quantum well: transition from di usive to ballistic regime.

V.T.Renard^{1,3}, O.A.Tkachenko^{2,1}, Z.D.Kvon^{2,1}, E.B.Olshanetsky^{2,1}, A.I.Toropov², J.C.Portal^{1,3,4}

¹ GHMFL, MPI-FKF/CNRS, BP-166, F-38042, Grenoble Cedex9, France;

² Institute of Sem iconductor Physics, Novosibirsk 630090, Russia;

⁴ Institut Universitaire de France, Toulouse, France;

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We report an experimental study of the quantum corrections to the longitudinal conductivity and the H all coe cient of a low mobility, high density two-dimensional two-dimensional electron gas in a A G aA s/G aA s/A G aA s quantum well in a wide temperature range (1.5 K - 110 K). This temperature range covers both the di usive and the ballistic interaction regimes for our samples. It was therefore possible to study the crossover region for the longitudinal conductivity and the H all e ect.

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I. IN TRODUCTION

At low temperatures the conductivity of a degenerated two-dimensional electron gas (2DEG) is governed by quantum corrections to the D rude conductivity $_{\rm D}$. In general, these corrections have two principal origins: the weak localization (W L) and the electron-electron (ee) interaction¹. Until recently our understanding of the interaction corrections to the conductivity of a 2D EG was based on the seem ingly unrelated theories developed for two opposite regimes: the diusive regime² $k_B T = h$ 1, and the ballistic regim $e^3 k_B T = h$ 1. In the di usive regime the quasi-particle interaction time $h=k_B T$ is larger than the momentum relaxation time and two interacting electrons experience multiple in purity scattering. In the ballistic regime the e-e interaction is mediated by a single in purity. Recently, Zala, Narozhny, and Aleiner (ZNA) have developed a new theory of the interaction related corrections to the conductivity^{4,5} that bridges the gap between the two theories known previously^{2,3}. One of the important conclusions of the new theory is that the interaction corrections to the conductivity in both regim es have a comm on origin: the coherent scattering of electrons by Freidel oscillations. Conform ably to the previous results^{2,3}, the new theory predicts a logarithm ic tem perature dependence of the longitudinal conductivity and the Hallcoe cient in the di usive regime, whereas in the ballistic regin e the tem perature dependence of these param eters becom es linear and T 1 respectively.

D espite a surge of experim ental activity 6,7,8,9,10,11 following the publication of the theory 4,5 so far no experim ent has been reported where the transition between the two regimes would have been clearly observed. One of the reasons is that the tem perature at which the transition is expected to occur is given by $k_{\rm B}\,T$ =h $\,$ 0.1, so that in the relatively high-m obility 2D systems that are commonly studied the transition temperature is by far too low (T < 100 mK for $\,>\,10^{-11}\,$ sec). Thus, the ZNA theory has so far been veri ed only in the intermediate

and ballistic regimes¹² ($k_B T = h = 0:1$ 10).

To shift the transition to higher temperatures one should use low mobility samples (sm all). At the same time high carrier densities N_s are necessary in order to maintain high conductivity and avoid strong localization. Moreover in high density 2D system s the characteristic parameter r_s = $E_{\rm C}$ =E $_{\rm F}$ / 1=N $_{\rm s}^{1=2}$, the ratio between C oulom b energy and Ferm i energy is small ($r_{\rm s}$ < 1) and hence the e ect of e-e interaction is relatively weak. In this case the Ferm i liquid interaction constant F_0 , the only parameter in the expressions for the quantum corrections to the conductivity in the theory 4 , can be calculated explicitly.

In this respect low -m obility high-density systems appear to o er certain advantages for testing the theory^{4,5}, as compared to high-m obility low -density systems. Indeed not only they provide an opportunity for studying an experimentally accessible temperature transition between the di usive and the ballistic interaction regimes but also the comparison between the theory and experiment requires not thing parameters.

The aim of the present work is to experim entally study the interaction related corrections to the conductivity and the Hall coe cient in a broad tem perature range covering both the di usive and ballistic interaction regim es and the transition between them. The experim ental results obtained in the weak interaction lim it are expected to allow for a parameter free com parison with the ZNA theory.

II. EXPERIMENTAL SET UP

The experimental samples had a 2DEG formed in a narrow (5 nm) A LG aA s/G aA s/A LG aA s quantum well - doped in the middle. Such doping results in a low mobility and a high carrier density. A detailed description of the structure can be found in Ref. 13. Two samples from the same wafer have been studied for which similar

 $^{^3\,}$ IN SA-Toulouse, 31077, Cedex 4, France; and



FIG.1: a) Longitudinal resistivity of the sam ple at N $_{\rm s}$ = 2:56 10^{12} cm 2 for tem perature= 1.4 K, 1.9 K, 3.1 K, 4 K, 7.2 K, 10.25 K, 15.45 K, 21.5 K, 31 K, 46.2 K, 62.8 K, 84.5 K and 110 K from top to bottom . b) Hall resistance at the same tem peratures (from top to bottom).

results were obtained. Here we present the data obtained for one of the sam ples with the following parameters at T = 1:4 K depending on prior illumination: the electron density N_s = (2:54 3:41) 10^2 cm² and the mobility = (380 560) cm²/Vs. The Hallbar shaped sam ples were studied between 1.4 K and 110 K in magnetic elds up to 15 T using a superconducting magnet and a VTI cryostat and also a ow cryostat (T > 5 K) placed in a 20 T resistivem agnet. The data was acquired via a standard four-term inal lock-in technique with the current 10 nA.

Fig. 1 shows the longitudinal and Hall resistances of the sample as a function of magnetic eld at temperatures up to 110 K. As can be seen both are strongly temperature dependent. Before analyzing the role of the quantum corrections in the behavior of the transport ∞ e cients shown in Fig.1, let us estimate the possible contribution from other unrelated temperature dependent factors.

First, since the measurements were performed up to relatively high tem peratures, the question of the role of phonon scattering becom es in portant. In this connection we believe that the following argument can be used. It is well known that in ultra-clean G aA s sam ples su ciently high values of mobility are reported even at liquid nitrogen tem peratures (see, for example R ef. 14,15, where = 4 10^5 cm²=V s at T = 77 K). At these tem perature the phonon scattering is the dom inant scattering mechanism in these samples and yet the mobilities are still a thousand tim es larger than in our sam ple. In our experin ent, the phonon contribution to the conductivity (and thus its variation with tem perature) is thus expected to be around 0.1% at the highest tem perature and can be neglected in the entire tem perature range.

Now, as can be seen in Fig. 1, the slope of the Hall resistance versus B dependence varies with T at low tem – peratures but remains practically constant for T > 20 K.

O nem ight argue that the behavior at low tem peratures could be due to a variation of the electron density with tem perature. However, we believe that this is not the case. Indeed, from the measurements carried out up to 20 T where the Shubnikov de Haas oscillations are better resolved, we nd that the density remains constant at T < 30 K. Also we nd that the density given by the SdH oscillations is the same as we get from the slope of the Hall resistance at T > 20 K where it is T - independent. We conclude therefore that the electron density remains constant in the entire experimental tem - perature range and all the data presented in Fig. 1 corresponds to N $_{\rm s} = 2.56$ 10^{12} cm 2 .

Having excluded the phonon scattering and the density variation as possible causes of the behavior shown in Fig. 1 we associate the observed temperature dependences with the quantum corrections to the transport coe cients. Our data will be analyzed in the fram ework of the recent theories^{4,5} valid for a degenerated 2DEG ($k_B T = E_F$). According to Ref. 13 only one subband is occupied in our quantum wells at N $_s = 2.56 = 10^{42}$ cm 2 . A lso $E_F = 1000$ K and so the theory^{4,5} should apply under our experimental conditions.

III. LONG IT UD IN AL CONDUCT IV IT Y AT $\mathbf{B}=\mathbf{0}\ \mathbf{T}$

Let us rst describe how the experimental quantum corrections were extracted from the row data and then turn to the analysis of the obtained corrections.

W ith the magnetic eld increasing the MR in Fig. 1a goes through two distinct types of behavior. An abrupt drop of resistance at low elds and then a much weaker magnetic eld dependence at higher B. It is easy to show that the possible classical MR described in Ref. 16 can be neglected in our sample. Indeed, the fraction of circling electrons, which in this theory are supposed to cause a deviation from the D rude theory is very sm all in our sam ples due to the low electron mobility. This means that the behavior in Fig. 1a must be attributed to quantum interference e ects, such as W L and the electron-electron interaction related corrections to the conductivity. As is well known the weak localization is suppressed at magnetic elds larger than $B_{tr} = h = (2el^2)$, where 1 is the mean free path. In our samples B_{tr} 1 T that roughly coincides with the eld at which the crossover from the one type of M R to the other takes place. We conclude therefore that the strong M R observed at low elds can be associated with the W L suppression in our samples and that the MR observed at higher elds must be attributed entirely to the e-e interaction e ects².

The longitudinal conductivity value is a sum of three components: the classical D rude conductivity, the W L contribution and the e-e interaction correction which is supposed to be independent of B as long as $k_B T = h 1$. For the correct evaluation of the interaction related correction at B = 0 T, the know ledge of the rst two contri-

butions to the conductivity is essential. Unfortunately, in our case there is no direct means of knowing the value of the D rude conductivity $_{\rm D}$ because of a considerable (up to 20%) variation of the zero eld conductivity with tem – perature. Nevertheless there exists an empirical method that can be used for the evaluation of the all three contributions to the conductivity at zero magnetic eld. This method has the advantage that one can forgo the usual procedure of tting the low eld data with the theoretical expressions for the W L magneto-resistance¹⁷, thus elim inating a possible source of error at this stage.

As a rst step of this method the experimental longitudinal conductivity is obtained by inverting the resistivity tensor using the data shown in Fig.1. The conductivity can be written as:

$$_{xx}$$
 (T;B) = $\frac{D}{1 + (!_{c})^{2}} + \frac{W_{xx}}{xx}$ (T;B) + $\frac{ee}{xx}$ (T); (1)

where $!_{c}$ is the cyclotron frequency, $\underset{xx}{\overset{W}{x}}^{I}_{x}$ and $\underset{xx}{\overset{ee}{e}}_{xx}$ are the W L and e-e interaction corrections respectively. The rst term corresponds to the classical T-independent M agneto-C onductivity (M C). The e-e interaction correction, B-independent in the di usive regin e² is expected to become m agnetic eld dependent in the opposite ballistic lim it. The weak localization corrections dom inates at low elds but is suppressed at (B > B_{tr}). Therefore, in the di usive lim it and for B >> B_{tr} the shape of the vs B dependence will be determined by the rst term in Eq. 1 while the e-e interaction correction to the conductivity should only result in a vertical shift of this classical

tivity should only result in a vertical shift of this classical contribution. Indeed, experimentally we not that with the W L completely suppressed at higher magnetic elds the M C corresponding to di erent temperatures forms parallel vertically shifted traces whose shape is given by the classical term in Eq.1. However, one can notice that at temperatures T > 30 K the shape of the curves begins to deviate slightly from that of the low temperature traces. This change of shape may be the consequence of the interaction correction becoming magnetic eld dependent at the crossover from the di usive to the ballistic regime.

It is possible to determ ine the momentum relaxation time by tting the curves for B > 6 T using the expression for the classical MC with as a tting parameter. This was done for all the tem peratures yielding the average value = 2:17 10¹⁴ s with a maximum deviation of 10%. This value of corresponds to D 6 é=h. Next, in order to elim in ate the W L contribution at B = 0the term $\frac{D}{1+(!c)^2}$ + $_{\rm xx}^{\rm ee}$ was extrapolated for each of the curves down to B = 0 T. Finally, to obtain the value of the e-e interaction correction corresponding to a given tem perature, the D rude conductivity was subtracted from the corresponding zero eld conductivity value obtained at the preceding step. Of course it is well to keep in m ind that this m ethod is correct only as long as the e-e correction is B-independent. That m eans that it is fully reliable only at low temperatures where the

M C traces are parallel. At T > 30 K it will give rise to an error increasing in proportion to the variation of the shape of the curves. To rem edy this we have also used an alternative way to estim ate the e-e interaction correction at high T which is as follows. The low temperature zero eld W L contribution determ ined at T < 30 K with the m ethod described above was extrapolated to higher tem – peratures using the common logarithm ic law expression¹. The e-e correction was then obtained by subtracting from the experimental zero eld conductivity the W L contribution obtained in this way together with the D rude conductivity.



FIG.2: Experim entaltem perature dependence of the e-e correction to conductivity obtained by the rst method (dots) and by the second method (opened squares), see the text. They are compared to the model of R ef. 4 (solid line). The inset shows the correction obtained using the rst approximation of $_{\rm D}$.

The results obtained by these two di erent m ethod are presented in the insert to Fig. 2. We realize that none of these two m ethods is fully accurate yet we suppose that the correct result for the e-e interaction contribution m ust lie som ew here between these two estim ates.

A coording to Ref. 4 the e-e interaction correction to conductivity is given by the following expressions:

$$\stackrel{\text{ee}}{}_{xx} = \quad _{C} + 3 \quad _{T} \tag{2}$$

$$c = \frac{e^2}{h} \frac{k_B T}{h} + 1 + \frac{3}{8} f (k_B T = h) + \frac{e^2}{2 + 2h} \ln \frac{h}{k_B T}$$
;

is the charge channel correction and

$$T = \frac{F_0}{[1 + F_0]} \frac{e^2}{h} \frac{k_B T}{h} = 1 - \frac{3}{8} t (k_B T = h; F_0)$$

$$1 - \frac{1}{F_0} \ln (1 + F_0) = \frac{e^2}{2 - h} \ln \frac{h}{k_B T};$$

is the correction in the triplet channel. The detailed expression of f(x) and t(x) can be found in Ref. 4. It is worth m entioning that for sm all r_s the interaction constant F_0 is an analytical function of parameter r_s (see Ref. 4). In our calculations we used the value $r_s = 0.35$ corresponding to the electron density in our sample.

Inset to Fig. 2 shows the theoretical curve calculated for our system parameters together with the experimentaldata points. As can be seen there is a system atic shift of the experimental points with respect to the theoretical curve. This shift can be attributed to a not quite accurate evaluation of the D rude conductivity. Indeed, a 10% variation of $_{\rm D}$ brings the experimental data points closer to the corresponding theoretical curve. A variation of this order of m agnitude lies within the experimental accuracy with which we determ ine $_{\rm D}$ and only weakly a ect the shape of the theoretical curve. Fig. 2 shows the results obtained using = 2:33 10⁻¹⁴ s ($_{\rm D} = 6:5$ e^2 =h). Thus a reasonably good agreement for the entire temperature range which also covers the intermediate regime is found.

Note that contrary to the previous works^{6,7,8,9,10,11} we have used no tting parameter. Moreover we nd that using the interaction constant F_0 as a tting parameter does not result in a better agreement between theory and experiment.

IV. HALL EFFECT

W e now turn to the analysis of the H all data presented in Figure.1b. A coording to R ef.5 the H all resistivity m ay be w ritten as:

$$x_{y} = {}_{H}^{D} + {}_{xy}^{C} + {}_{xy}^{T}$$
(3)

where $_{H}^{D}$ is the classical H all resistivity and $_{xy}^{C}$; $_{xy}^{T}$ are the corrections in the charge and triplet channel. These corrections are given as follows:

$$\frac{\frac{c_{Xy}}{D}}{\frac{D}{H}} = \frac{2}{D} \frac{G_0}{D} \ln 1 + \frac{h}{k_B T}$$
(4)

$$\frac{\frac{T}{Xy}}{\frac{D}{H}} = \frac{6}{2} \frac{G_0}{D} h (F_0) \ln 1 + \frac{h}{k_B T}$$

The detailed expression for h(x) can be found in Ref.5, = $\frac{11}{192}$ and the value of $_{H}^{D}$ is obtained from the high tem perature curves for which $_{xy}$! 0.

Therefore according to the theory of the e-e interaction⁵ one should observe a logarithm ic tem perature dependence of $_{xy} = \frac{D}{H}$ 1 in the di usive regime replaced by a hyperbolic decrease 1=T at higher tem peratures. Figure 3 shows how this prediction works in our case.

A simple calculation (carried out without any attempt at thing the experiment) results in the dashed curve. 4



FIG. 3: Temperature dependence of the Hall coe cient (dots) compared to Eq.3 (dash line) and to Eq.3 with $=\frac{3}{192}$ (solid line). The inset shows the transverse conductivity as function of T for two di erent values of magnetic elds.

In this calculation we used the value $F_0 ! \frac{1}{2} \frac{r_{sp}}{r_s + r_2} =$

0:1, calculated with the expression recommended in the theory⁴ for the weak interaction limit. On the whole there is a qualitative agreement between theory and experiment (black dots) but the quantitative agreement is lacking. Using F_0 as a tring parameter does not improve the agreement. Nevertheless we have found, that if the coecient $= \frac{11}{192}$ is replaced by $= \frac{3}{192}$, then the theoretical curve (the solid line) to the experimental dependence quite well. This result might be related to an anisotropy of electron scattering in the sample which reduces the electron return probability and so weakens the correction at low elds (! c << 1). The reduction of the pre-factor could just be the way in which this anisotropy reveals itself since the correction is proportional to in the ballistic limit.

Finally, in the inset to Figure. 3 we show the experim ental data points for the transverse conductivity as a function of tem perature for two di erent values of m agnetic eld. In our opinion these dependencies can serve as a good illustration for the transition between the diffusive and ballistic interaction regimes. Indeed, there should be no contribution of the W L² to the transverse conductivity tensor component. Also, in the di usive $ee_{xy} = 0$. Thus, one would expect that regim e² would be T-independent at low T-range which is exactly what we see in the Inset. As for the interm ediate and ballistic regime, up to date there have been no predictionsconcerning xy. A coording to R ef. 4 the transition between the di usive and the ballistic regime occurs at 0:1 corresponding to T 30 K in our sam ple. k_B T =h One can see that at about this tem perature xy starts rapidly increasing. One can conclude that the theoretical results for xy in the di usive lim it are no longer valid in the ballistic transport regime. To our know ledge this is the rst m easurem ents of the xy tem perature dependence in the ballistic regime.

V. CONCLUSION

In conclusion, we have observed the transition from the di usive to the ballistic regime in the weak interaction limit for the longitudinal conductivity, the Hall coe cient, and the Hall conductivity in a high density low m obility 2D EG.We nd our experimental results to be in a good qualitative agreement with ZNA theory.

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